

SEMITOP[®] 3

IGBT Module

SK13GD063

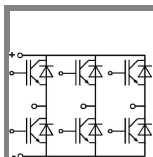
Preliminary Data

Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- N channel, homogeneous Silicon structure (NPT-Non punchthrough IGBT)
- High short circuit capability
- Low tail current with low temperature dependence
- UL recognized, file no. E63532

Typical Applications

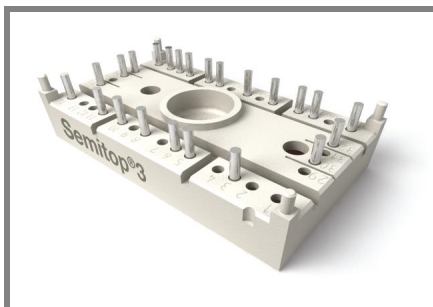
- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS



GD

Absolute Maximum Ratings		$T_s = 25\text{ °C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT			
V_{CES}	$T_j = 25\text{ °C}$	600	V
I_C	$T_j = 125\text{ °C}$	$T_s = 25\text{ °C}$	18 A
		$T_s = 80\text{ °C}$	13 A
I_{CRM}	$I_{CRM} = 2 \times I_{Cnom}$	20	A
V_{GES}		± 20	V
t_{psc}	$V_{CC} = 300\text{ V}$; $V_{GE} \leq 20\text{ V}$; $T_j = 125\text{ °C}$ $V_{CES} < 600\text{ V}$	10	μs
Inverse Diode			
I_F	$T_j = 125\text{ °C}$	$T_s = 25\text{ °C}$	22 A
		$T_s = 80\text{ °C}$	15 A
I_{FRM}	$I_{FRM} = 2 \times I_{Fnom}$		A
I_{FSM}	$t_p = 10\text{ ms}$; half sine wave $T_j = 150\text{ °C}$	100	A
Module			
$I_{t(RMS)}$			A
T_{vj}		-40 ... +150	$^{\circ}\text{C}$
T_{stg}		-40 ... +125	$^{\circ}\text{C}$
V_{isol}	AC, 1 min.	2500	V

Characteristics		$T_s = 25\text{ °C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 0,35\text{ mA}$	4,5	5,5	6,5	V
I_{CES}	$V_{GE} = 0\text{ V}$, $V_{CE} = V_{CES}$	$T_j = 25\text{ °C}$		0,05	mA
		$T_j = 125\text{ °C}$			mA
I_{GES}	$V_{CE} = 0\text{ V}$, $V_{GE} = 30\text{ V}$	$T_j = 25\text{ °C}$		120	nA
		$T_j = 125\text{ °C}$			nA
V_{CE0}		$T_j = 25\text{ °C}$	1		V
		$T_j = 125\text{ °C}$	1,1		V
r_{CE}	$V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}$	110		$\text{m}\Omega$
		$T_j = 125\text{ °C}$	90		$\text{m}\Omega$
$V_{CE(sat)}$	$I_{Cnom} = 10\text{ A}$, $V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}_{chiplev.}$	2,1	2,5	V
		$T_j = 125\text{ °C}_{chiplev.}$	2	2,3	V
C_{ies}	$V_{CE} = 25$, $V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	0,45		nF
C_{oes}					nF
C_{res}			0,04		nF
Q_G	$V_{GE} = 0 \dots 20\text{ V}$		54		nC
$t_{d(on)}$	$R_{Gon} = 100\ \Omega$	$V_{CC} = 300\text{ V}$ $I_{Cnom} = 10\text{ A}$ $T_j = 125\text{ °C}$	45		ns
t_r			45		ns
E_{on}			0,6		mJ
$t_{d(off)}$	$R_{Goff} = 100\ \Omega$	$T_j = 125\text{ °C}$ $V_{GE} = \pm 15\text{ V}$	250		ns
t_f			20		ns
E_{off}			0,4		mJ
$R_{th(j-s)}$	per IGBT			2	K/W



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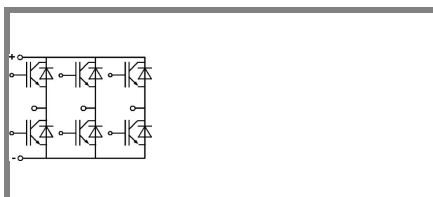
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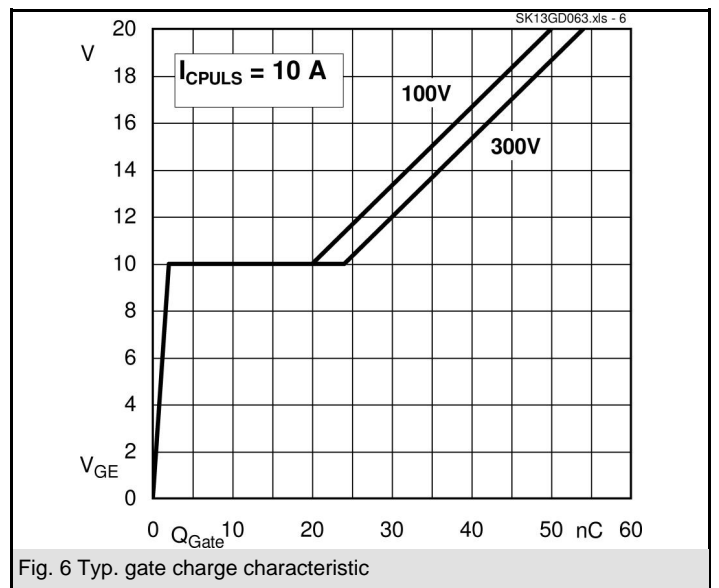
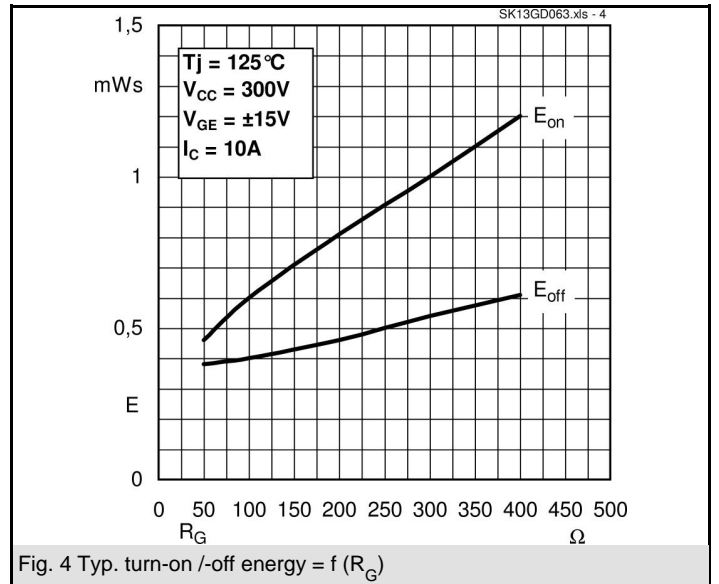
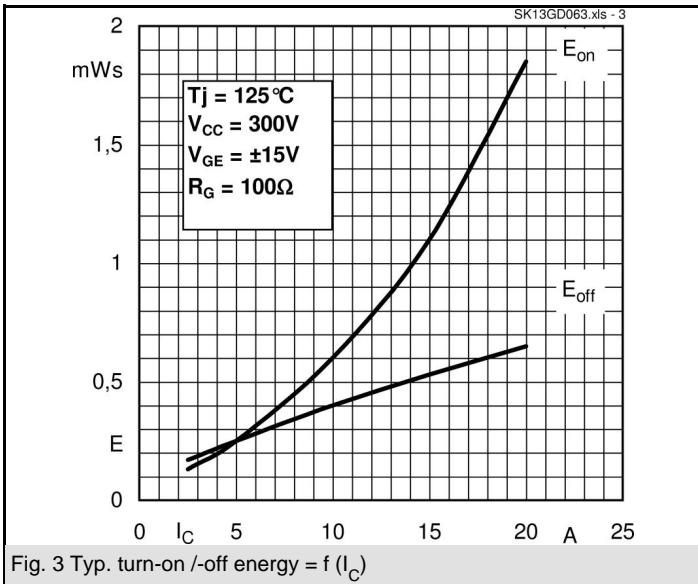
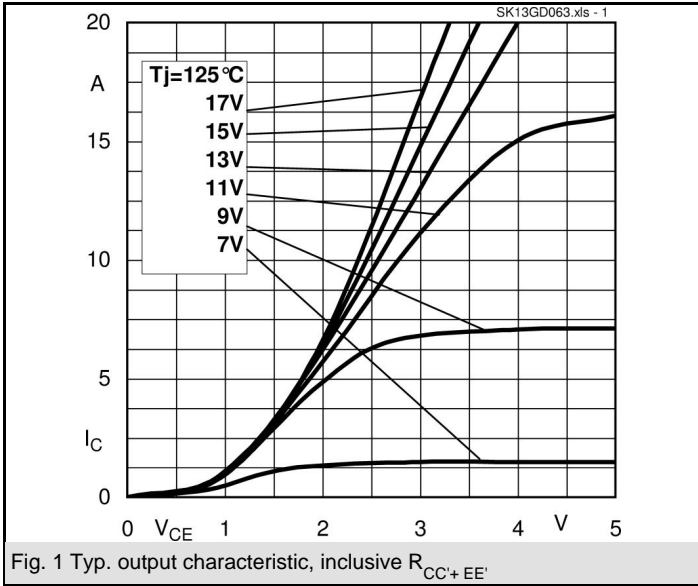
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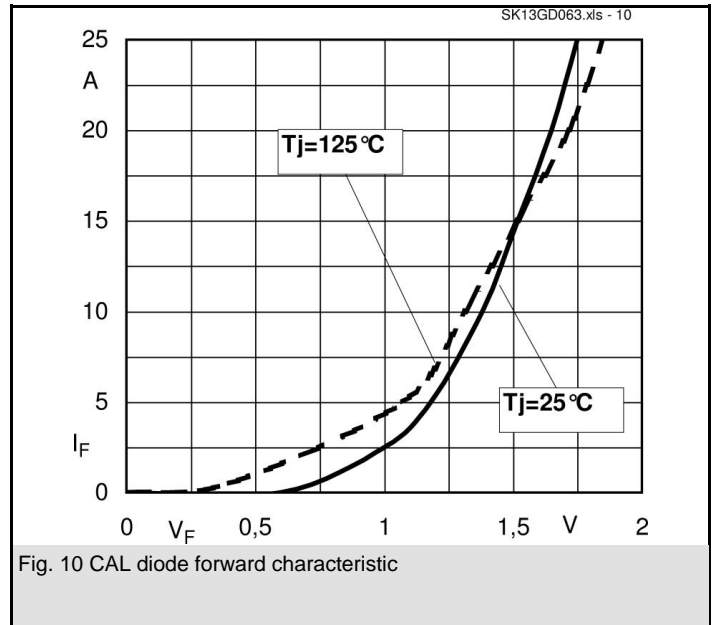
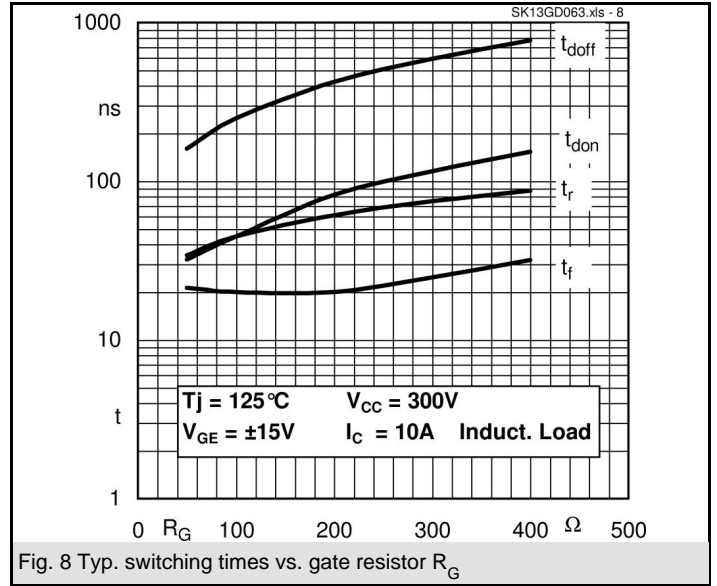
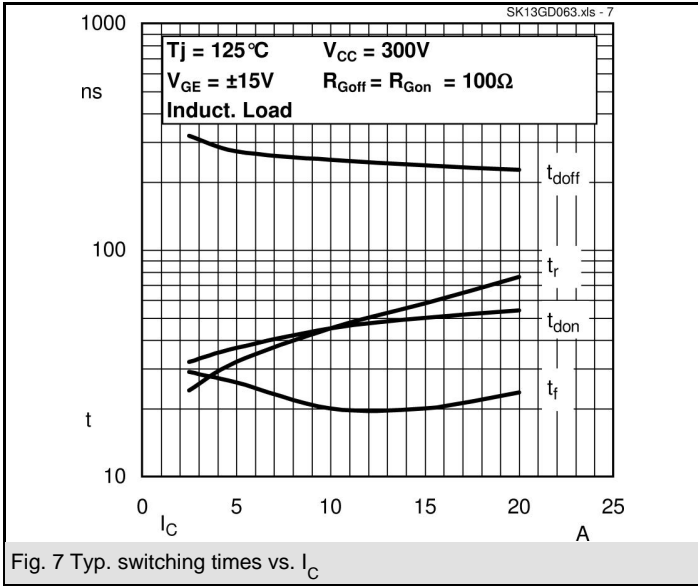
Characteristics

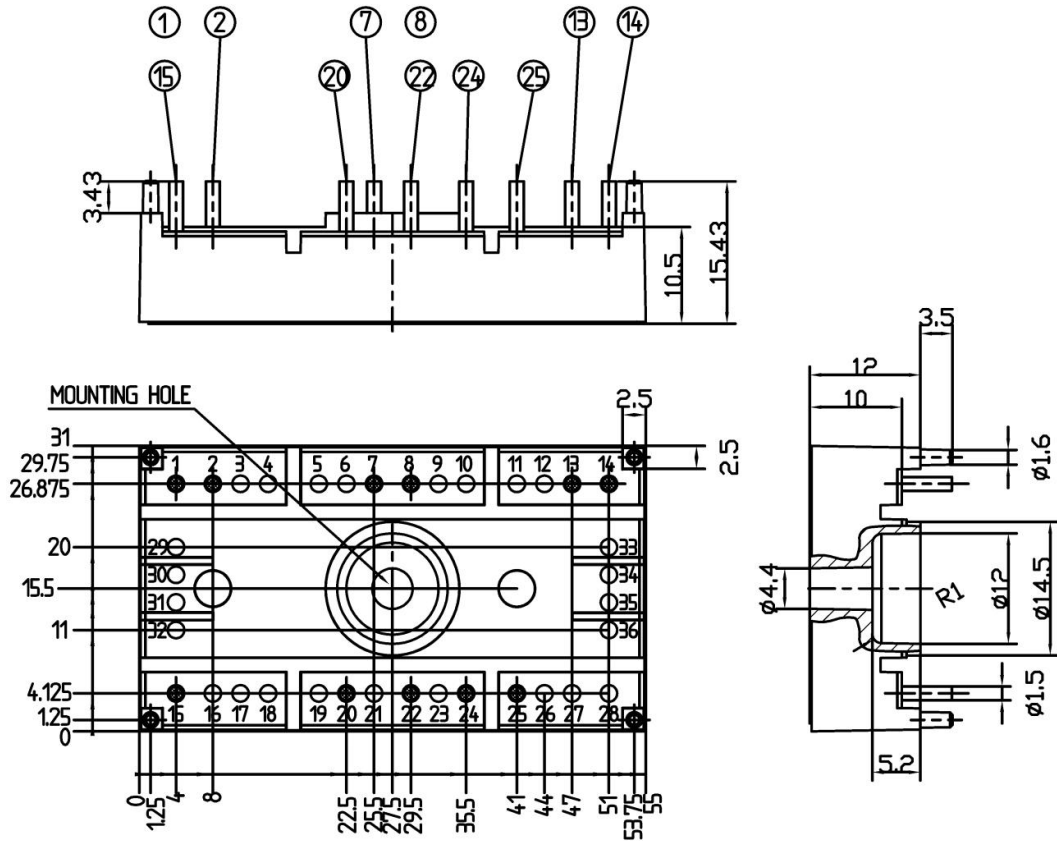
Symbol	Conditions	min.	typ.	max.	Units	
Inverse Diode						
$V_F = V_{EC}$	$I_{Fnom} = 10 \text{ A}; V_{GE} = 0 \text{ V}$		$T_j = 25 \text{ }^\circ\text{C}_{\text{chiplev.}}$	1,45	1,7	V
			$T_j = 125 \text{ }^\circ\text{C}_{\text{chiplev.}}$	1,4	1,75	V
V_{F0}			$T_j = 125 \text{ }^\circ\text{C}$	0,85	0,9	V
r_F			$T_j = 125 \text{ }^\circ\text{C}$	55	80	m Ω
I_{RRM}	$I_{Fnom} = 10 \text{ A}$		$T_j = 125 \text{ }^\circ\text{C}$	6,5		A
Q_{rr}	$di/dt = -200 \text{ A}/\mu\text{s}$			1		μC
E_{rr}	$V_{CC} = 300 \text{ V}$			0,1		mJ
$R_{th(j-s)D}$	per diode			2,3		K/W
M_s	to heat sink M1	2,25		2,5		Nm
w			30			g

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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Case T12 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)

